



### **TECHNICAL DATA SHEET**

PE15A5084

The PE15A5084 is a Class AB high power amplifier that operates in high VHF through S bands from 200 MHz to 2600 MHz and generates 10 Watts (typ) of CW RF power. The module utilizes the latest Gallium Nitride (GaN) semiconductor technology with 40% power added efficiency. The amplifier package design features an extremely small form factor of just 2.84in³ that's ideal for size, weight, and power (SWaP) constrained applications used in broadband RF telemetry, tactical communication, electronic warfare, and unmanned aircraft systems, as well as software defined radios. Impressive typical performance includes 46 dB of linear gain, 2:0:1 VSWR, +44 dBm third order intercept point, and harmonic suppression of -15 dBc. Operating voltage is +28 Vdc with 1.4A of DC current. Additional features include overvoltage protection, reverse voltage protection, and logic on/off control. The rugged Mil-Grade assembly supports female SMA RF input/output connectors and a micro-D 9 pin socket command control connector with an accessory cable assembly included. The operating baseplate temperature range is -40°C to +85°C and the unit is guaranteed to withstand up to 95% relative humidity, altitude levels up to 30,000 ft, and random vibration and shock profiles (see chart below). Pasternak also offers an accessory Harmonic filter option, model PEHFL0000 that can be used at the output of the PE15A5084 power amplifier. This lowpass RF filter has low insertion loss with power handling up to 50W and specifically designed to reduce harmonics at the output of transmitters operating at up through L & S Bands and offers rejection levels of greater than 25 dB from 3.25 GHz to 5 GHz. The filter is offered in a miniature SMA connectorized package.

#### **Features**

- 10W GaN High Power Amplifier
- High VHF through S Band Class AB Design
- Frequency Range: 200 MHz to 2600 MHz
- 46 dB linear Gain
- VSWR: 2.0:1
- +44 dBm IP3
- PAE: 40%

- Extremely Small Form Factor Rugged Mil-Grade Package
- 50 Ohm Design
- Female SMA RF Connectors
- +28Vdc @0.1.4A DC current
- -40°C to +85°C Operating Baseplate Temperature
- Output Harmonic Filter Accessory Option

#### **Applications**

- · Broadband RF Telemetry
- RF Communications Systems
- Electronic Warfare Airborne Electronic Attack
- Unmanned Aircraft Systems (UAS)
- Unmanned Ground Vehicles (UGV), Software Defined Radios
- Data Links
- Transmitters
- Test & Measurement
- Telecom Infrastructure

#### Electrical Specifications (TA = +25°C, DC Voltage = 28Volts, DC Current = 1.4A)

Description	Minimum	Typical	Maximum	Units
Frequency Range	0.2		2.6	GHz
Small Signal Gain		46		dB
Gain Flatness		±4		dB
Input Power (CW)		+0		dBm
Pout at Sat.	+7	+10		dBm
Efficiency (PAE)		40		%
Output Power at 1 dB Compression Point		+33		dBm
Output 3rd Order Intercept Point		+44		dBm
Output Mismatch			10:1	
2nd Harmonics		-10		dBc

Click the following link (or enter part number in "SEARCH" on website) to obtain additional part information including price, inventory and certifications: 10 Watt GaN Power Amplifier, 200 MHz to 2600 MHz, Class AB, High VHF through S Bands, 40% Efficiency, 28V, SMA PE15A5084

Pasternack Enterprises, Inc. • P.O. Box 16759, Irvine, CA 92623 **Phone:** (866) 727-8376 or (949) 261-1920 • **Fax:** (949) 261-7451

Sales@Pasternack.com • Techsupport@Pasternack.com





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3rd Harmonics		-15		dBc
Impedance (Input)		50		Ohms
Impedance (Output)		50		Ohms
Input VSWR		2:1		
Operating DC Voltage	11	28	32	Volts
Operating DC Current		1.4	1.8	Α
Quiescent Current Biased ()		400		mA
Operating Temperature Range	-40		+85	°C

#### Performance by Frequency

Description	F1	F2	F3	Units
Frequency Condition	200	1400	2600	MHz
Output Power @ 1dB Compression, Typ	26	25	33	dBm
Small Signal Gain, Typ (@-30 dBm Input)	46	46	43	dB
Third Order Intercept Point	42	44	41	dBm

### **Absolute Maximum Rating**

Parameter	Rating	Unit
Max Device Voltage	32	V
Max Device Current	3.0	А
Max RF Input Power, $Z_L = 50 \Omega$	10	dBm
Max Operating Temperature (ambient)	60	°C
Max Operating Temperature (baseplate)	85	°C
Max Storage Temperature	85	°C



ESD Sensitive Material, Transport material in Approved ESD bags. Handle only in approved ESD Workstation.

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#### **Mechanical Specifications**

S	i	7	_
J	•	_	c

Length
Width
Height
Weight
Input Connector
Output Connector
Bias Connector

2.34 in [59.44 mm] 1.96 in [49.78 mm] 0.62 in [15.75 mm] 0.2 lbs [90.72 g] SMA Female SMA Female 9-Pin Micro-D Socket

#### **Environmental Specifications**



Temperature

Operating Range Storage Range

Humidity Altitude -40 to +85 deg C -55 to +85 deg C

95% Non-Condensing MIL-STD-810F Method 5004

Compliance Certifications (see product page for current document)

#### **Plotted and Other Data**

Notes:

· Values at +25 °C, sea level

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### **Amplifier Power-up Precautions**

- 1.) Confirm that proper ESD precautions and controls are always in place before handling any Amplifier module.
- 2.) Confirm adequate thermal management is in place to effectively dissipate heat away from the Amplifier package. The Amplifier operational baseplate temperature must be within the operational temperature range stated in the Amplifier datasheet. Depending on the design and thermal requirements, using a heatsink with cooling fan is always recommended for safe reliable operation. A heat sink without a cooling fan may also be used. Damage caused from overheating will void the warranty.
- 3.) Confirm adequate system grounding is established. The DC power supply and Amplifier must have a common ground in order to operate properly.
- 4.) Power Amplifiers may require additional DC Current when initially powered-up. Depending on the design, the input current draw could range from an additional 10% to 100% above the maximum rated DC current of the Amplifier. This varies based on product part number.
- 5.) Confirm the DC power supply, if limited, is set to allow for additional start-up current that's rated for the Power Amplifier.
- 6.) Confirm the system is designed and calibrated for 50 ohms. Any impedance mismatch may cause performance issues.
- 7.) Perform a CALIBRATION (if required) with the loads before connecting the Amplifier to the Network Analyzer to ensure proper performance.
- 8.) Use a fixed attenuator between the signal source and input port of the Amplifier to optimize the input VSWR match.
- 9.) Confirm the input power level at the input port of the amplifier does not exceed the maximum rated limit for input power (as stated in the Amplifier datasheet).

 $P_{in}$  for Small Signal Gain = P1dB-SSG-10 dB  $P_{in}$  for P1dB = P1dB-SSG+1 dB

- 10.) Confirm the Network Analyzer is always connected to the Amplifier <u>first</u> before DC power is applied to the Amplifier.
- 11.) As long as the input and output ports of the amplifier are connected to a 500hm load and RF signal power is applied, the Amplifier can be powered up with DC voltage.
- 12.) Confirm the Amplifier output load is matched for a 50 Ohm impedance and will not exceed the maximum rated VSWR or Return Loss limit for the Amplifier. Exceeding the maximum rated VSWR or Return Loss limit will result in reflected signal power that could damage the Amplifier and void the warranty.
- 13.) **Power Amplifier connected to an Antenna for signal transmission** It's strongly recommended to use a high power fixed attenuator pad or an Isolator between the output port of the Amplifier and input port to the antenna. Any reflected signal power due to impedance mismatch will likely damage the Amplifier and void the warranty.
- 14.) The attenuator or isolator used at the output port of the Amplifier must be rated to handle the output power level and operational frequency band of the amplifier.

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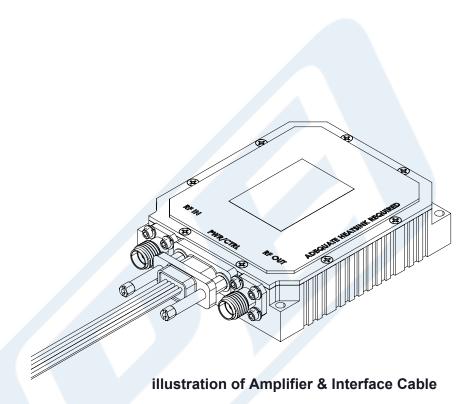
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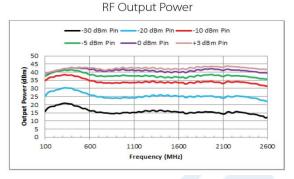




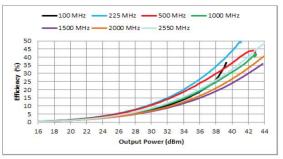
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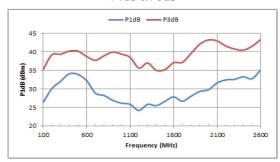
#### **Typical Performance Data**



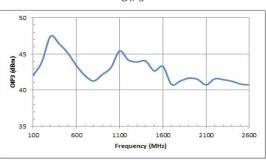
Efficiency vs Power Output



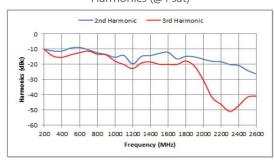
P1dB & P3dB



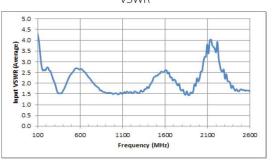
OIP3



Harmonics (@ Psat)



VSWR



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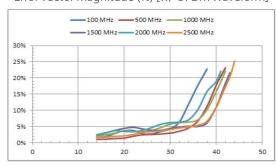




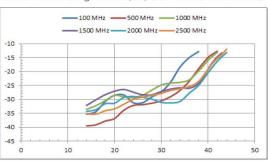
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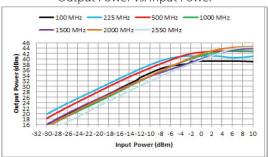
Error Vector Magnitude (%) [w/ OFDM Waveform]



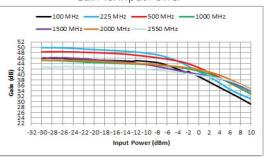




Output Power vs. Input Power



Gain vs. Input Power



10 Watt GaN Power Amplifier, 200 MHz to 2600 MHz, Class AB, High VHF through S Bands, 40% Efficiency, 28V, SMA from Pasternack Enterprises has same day shipment for domestic and International orders. Our RF, microwave and millimeter wave products maintain a 99.4% availability and are part of the broadest selection in the industry.

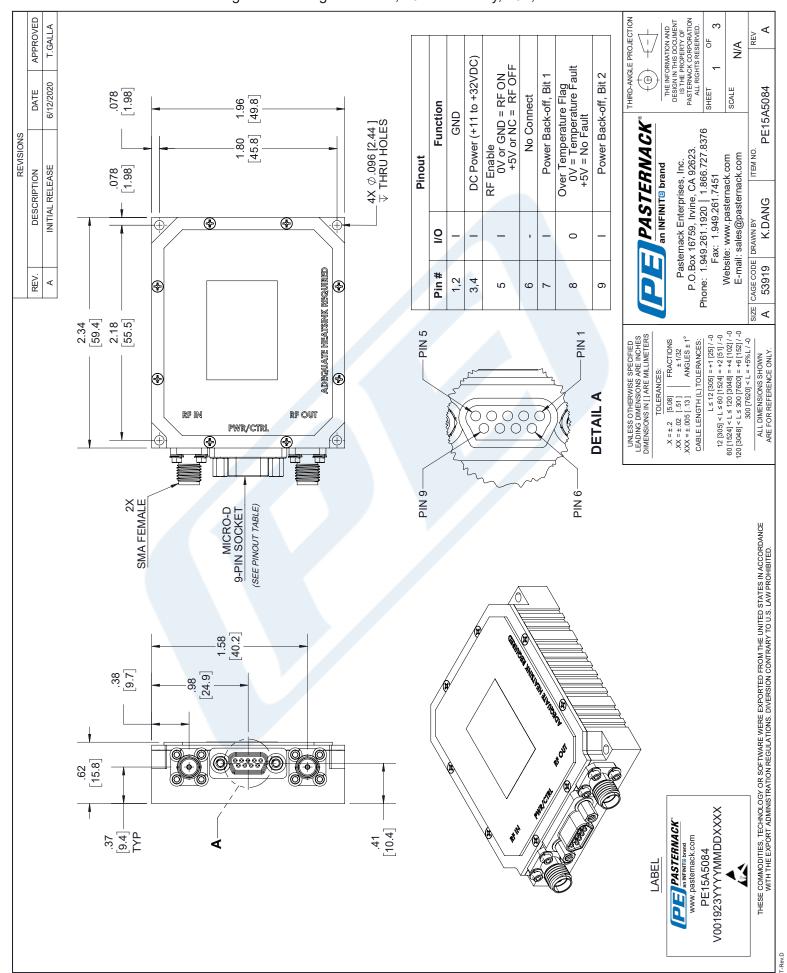
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URL: https://www.pasternack.com/46-db-gain-2.6-ghz-medium-power-high-gain-amplifier-sma-pe15a5084-p.aspx

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## PE15A5084 CAD Drawing

10 Watt GaN Power Amplifier, 200 MHz to 2600 MHz, Class AB, High VHF through S Bands, 40% Efficiency, 28V, SMA



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